NSN 5961-01-222-8447

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-222-8447 **Inclosure Material:** Metal all transistor **Overall Length:** 0.240 inches and 0.260 inches all transistor **Terminal Length:** 1.500 inches all transistor **Overall Diameter:** 0.335 inches and 0.370 inches all transistor **Function For Which Designed:** Switching **Internal Configuration:** Junction contact all transistor **Internal Junction Configuration:** Pnp all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Terminal Circle Diameter:** 0.200 inches all transistor **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 600.00 milliamperes collector current, dc all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction all transistor **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: